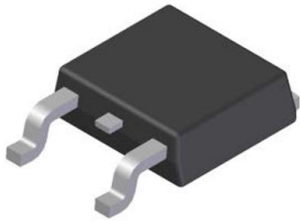


ZXT953KTC Datasheet

www.digi-electronics.com



| | |
|------------------------------|--|
| DiGi Electronics Part Number | ZXT953KTC-DG |
| Manufacturer | Diodes Incorporated |
| Manufacturer Product Number | ZXT953KTC |
| Description | TRANS PNP 100V 5A TO252-3 |
| Detailed Description | Bipolar (BJT) Transistor PNP 100 V 5 A 125MHz 4.2 W Surface Mount TO-252-3 |

<https://www.DiGi-Electronics.com>



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

ZXT953KTC

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

100 V

Current - Collector Cutoff (Max):

20nA (ICBO)

Power - Max:

4.2 W

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

TO-252-3, DPAK (2 Leads + Tab), SC-63

Base Product Number:

ZXT953

Manufacturer:

Diodes Incorporated

Product Status:

Active

Current - Collector (Ic) (Max):

5 A

Vce Saturation (Max) @ Ib, Ic:

390mV @ 500mA, 5A

DC Current Gain (hFE) (Min) @ Ic, Vce:

100 @ 1A, 1V

Frequency - Transition:

125MHz

Mounting Type:

Surface Mount

Supplier Device Package:

TO-252-3

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

100V PNP LOW SATURATION MEDIUM POWER TRANSISTOR

Features

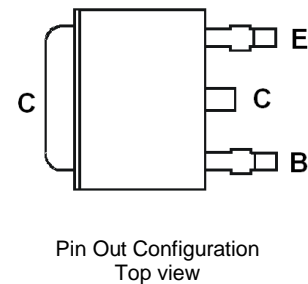
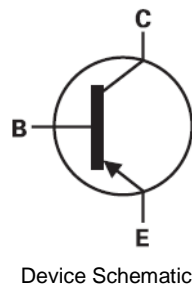
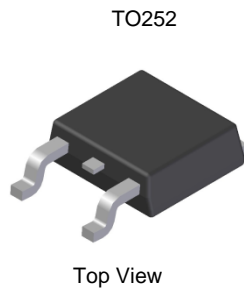
- $BV_{CEO} > -100V$
- $I_C = -5A$ Continuous Collector Current
- $I_{CM} = -10A$ Peak Collector Current
- $R_{SAT} = 67m\Omega$ Typical for Low Equivalent On Resistance
- Low Saturation Voltage
- High Gain Hold-Up (100 min @ 1 A)
- **Lead-Free Finish; RoHS Compliant (Note 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish — Matte Tin; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.34 grams (Approximate)

Application

- DC-DC Converters
- Power Switches
- Motor Control
- Automotive Circuits
- Inverter Circuits

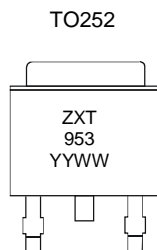


Ordering Information (Note 4)

| Product | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-----------|------------|---------|--------------------|-----------------|-------------------|
| ZXT953KTC | AEC-Q101 | ZXT953 | 13 | 16 | 2,500 |

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



ZXT953 = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Digit of Year (ex: 15 = 2015)
 WW = Week Code (01 – 53)

Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------|-------|------|
| Collector-Base Voltage | BV_{CBO} | -140 | V |
| Collector-Base Voltage | BV_{CER} | -140 | V |
| Collector-Emitter Voltage | V_{CEO} | -100 | V |
| Emitter-Base Voltage | V_{EBO} | -7 | V |
| Continuous Collector Current | I_C | -5 | A |
| Base Current | I_B | -0.5 | A |
| Peak Pulse Collector Current | I_{CM} | -10 | A |

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

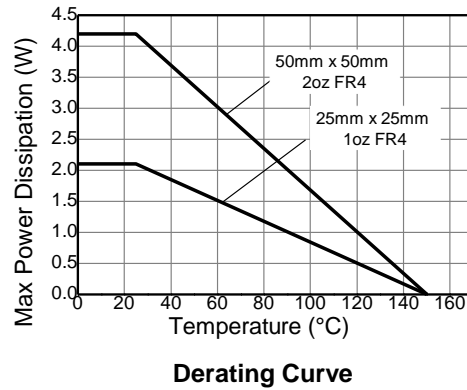
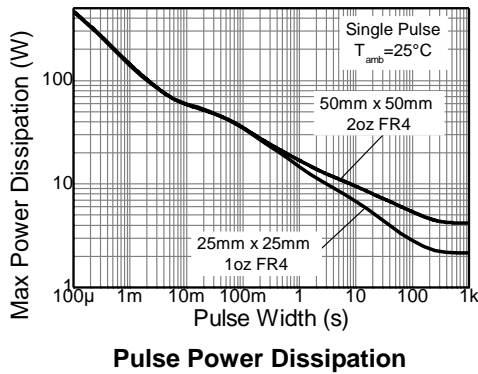
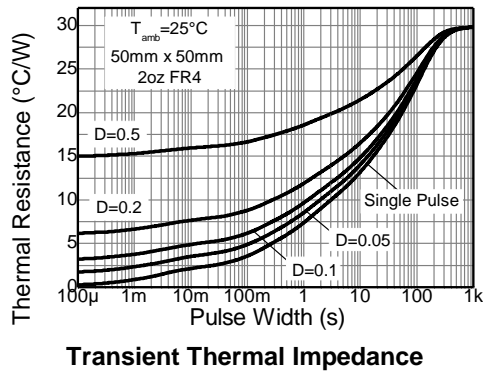
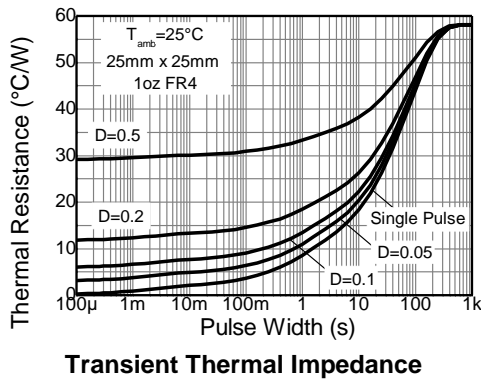
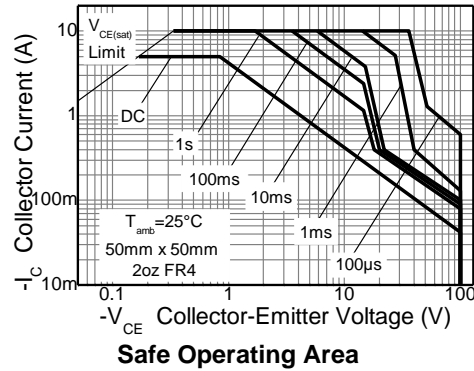
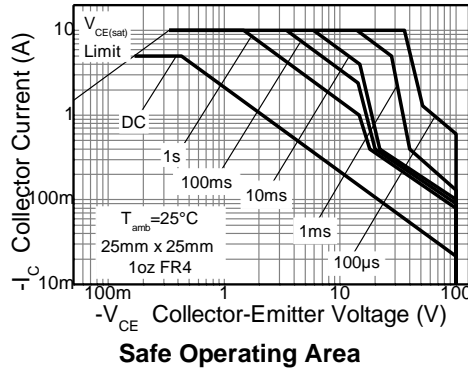
| Characteristic | Symbol | Value | Unit |
|---|-----------------|-------------|--------------------|
| Power Dissipation | P_D | (Note 5) | 2.1 |
| | | (Note 6) | 3.2 |
| | | (Note 7) | 4.2 |
| Thermal Resistance, Junction to Ambient Air | $R_{\theta JA}$ | (Note 5) | 59 |
| | | (Note 6) | 39 |
| | | (Note 7) | 30 |
| Thermal Resistance, Junction to Leads | $R_{\theta JL}$ | 1.8 | $^\circ\text{C/W}$ |
| Operating and Storage Temperature Range | T_J, T_{STG} | -55 to +150 | $^\circ\text{C}$ |

ESD Ratings (Note 9)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | C |

- Notes:
- For a device mounted with the exposed collector pad on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 - Same as Note 5, except the device is mounted on 50mm x 50mm with 1oz copper.
 - Same as Note 5, except the device is mounted on 50mm x 50mm with 2oz copper.
 - Thermal resistance from junction to solder-point (at the end of the collector lead).
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information



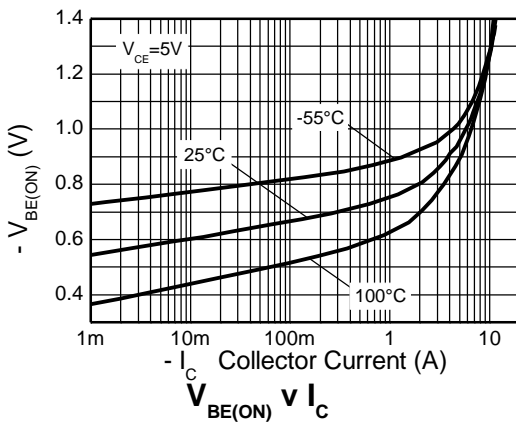
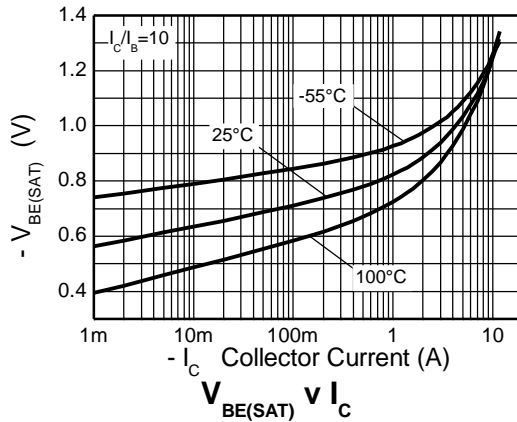
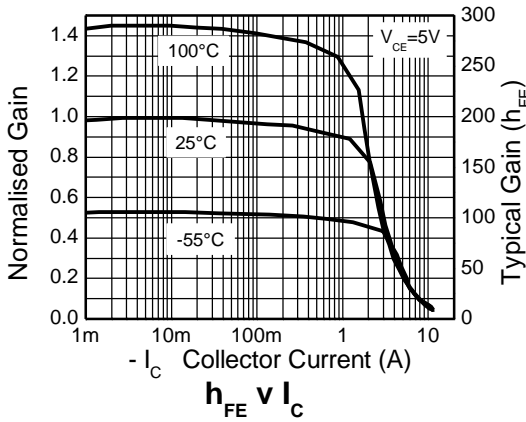
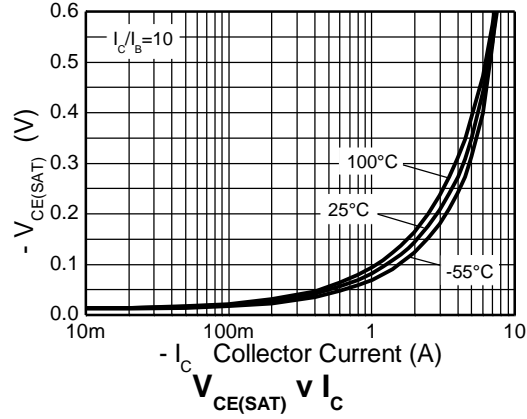
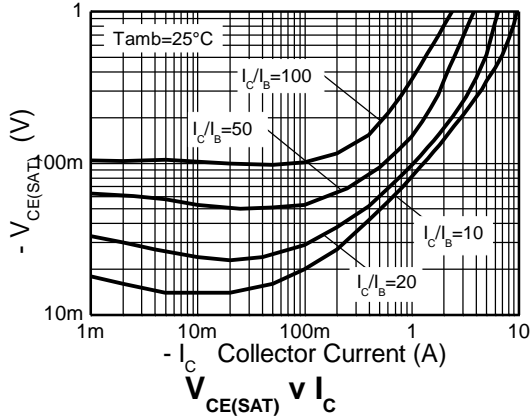

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ. | Max | Unit | Test Condition |
|--|-------------------------------------|------------------------|----------------------------|-----------------------------|------|---|
| Collector-Base Breakdown Voltage | BV _{CBO} | -140 | -170 | - | V | I _C = -100μA |
| Collector-Base Breakdown Voltage | BV _{CER} | -140 | -170 | - | V | I _C = -1μA, R _{BE} ≤ 1kΩ |
| Collector-Emitter Breakdown Voltage (Note 10) | BV _{CEO} | -100 | -125 | - | V | I _C = -10mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -7 | -8.1 | - | V | I _E = -100μA |
| Collector Cut-Off Current | I _{CBO} | - | <1 | -20 | nA | V _{CB} = -100V |
| Emitter Cut-Off Current | I _{EBO} | - | <1 | -10 | nA | V _{EB} = -6V |
| Emitter Cut-Off Current | I _{CER} | - | <1 | -20 | nA | V _{CE} = -100V, R _{BE} ≤ 1kΩ |
| DC Current Transfer Static Ratio (Note 10) | h _{FE} | 100 100 50 15 | 220 200 85 30 | - 300 - - | - | I _C = -10mA, V _{CE} = -1V I _C = -1A, V _{CE} = -1V I _C = -3A, V _{CE} = -1V I _C = -5A, V _{CE} = -1V |
| Collector-Emitter Saturation Voltage (Note 10) | V _{CE(sat)} | - - - - | -20 -80 -140 -335 | -30 -100 -175 -390 | mV | I _C = -0.1A, I _B = -10mA I _C = -1A, I _B = -100mA I _C = -2A, I _B = -200mA I _C = -5A, I _B = -500mA |
| Base-Emitter Saturation Voltage (Note 10) | V _{BE(sat)} | - | -1.01 | -1.1 | V | I _C = -5A, I _B = -500mA |
| Base-Emitter Turn-On Voltage (Note 10) | V _{BE(on)} | - | -0.94 | -1.05 | V | I _C = -5A, V _{CE} = -1V |
| Transitional Frequency | f _T | - | 125 | - | MHz | I _C = -100mA, V _{CE} = -10V f = 50MHz |
| Output Capacitance | C _{OBO} | - | 65 | - | pF | V _{CB} = -10V, f = 1MHz, |
| Switching Times | t _{ON} t _{OFF} | - | 110 460 | - | nS | I _C = -2A, V _{CC} = -10V, I _{B1} = I _{B2} = -200mA |

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

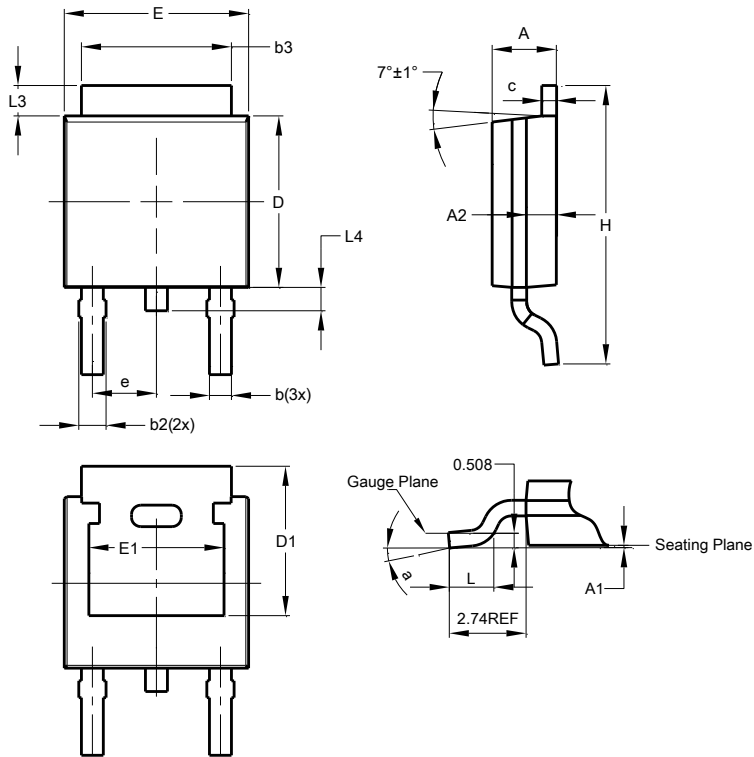


Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

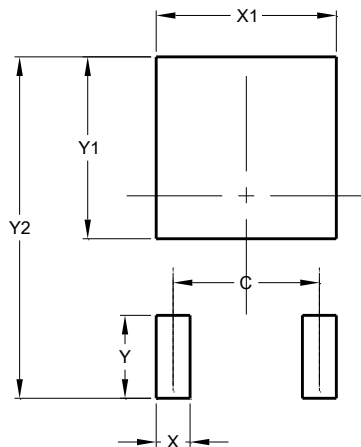
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| TO252 (DPAK) | | | |
|-----------------------------|------|-------|-------|
| Dim | Min | Max | Typ |
| A | 2.19 | 2.39 | 2.29 |
| A1 | 0.00 | 0.13 | 0.08 |
| A2 | 0.97 | 1.17 | 1.07 |
| b | 0.64 | 0.88 | 0.783 |
| b2 | 0.76 | 1.14 | 0.95 |
| b3 | 5.21 | 5.46 | 5.33 |
| c | 0.45 | 0.58 | 0.531 |
| D | 6.00 | 6.20 | 6.10 |
| D1 | 5.21 | - | - |
| e | - | - | 2.286 |
| E | 6.45 | 6.70 | 6.58 |
| E1 | 4.32 | - | - |
| H | 9.40 | 10.41 | 9.91 |
| L | 1.40 | 1.78 | 1.59 |
| L3 | 0.88 | 1.27 | 1.08 |
| L4 | 0.64 | 1.02 | 0.83 |
| a | 0° | 10° | - |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 4.572 |
| X | 1.060 |
| X1 | 5.632 |
| Y | 2.600 |
| Y1 | 5.700 |
| Y2 | 10.700 |

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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ZXT953K

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